Microsemi

KV1911A - KV1991A

VARACTOR DIODES

UHF Microwave Super-Hyperabrupt Junction

RoHS Compliant





DESCRIPTION

The KV1900 series of Super Hyperabrupt Varactor diodes combines low voltage with high ratio tuning. They feature grown junction mesa technology for the highest Q commercially available. Passivation is our tough MIL-Spec ceramic glass for lowest leakage even at temperature extremes or dense SiO₂ for lowest 1/F noise. They are available in a wide range of package styles including chip (style 00) and most other conventional ceramic microwave packages.

When ordering, specify the desired case style by adding its number as a suffix to the basic model number. For more details on KV19x1A Super Hyperabrupt Varactors in popular high performance surface mount packages, see the KV19x2A & KV19x3A series products.

KEY FEATURES

- Available as packaged devices or as chips for hybrid applications
- Typical 4:1 Tuning Range
- Ultrahigh Q
- Values for frequencies from UHF through X band.

APPLICATIONS

The KV19x1A series is an ideal choice for low voltage battery supplied VCOs covering frequency ranges from UHF through 12 GHz. They are used widely in analog phase shifters and phase modulators in microwave communications. They are also excellent choices for higher overtone, high pull VCXO and TCXO applications.

APPLICATIONS/BENEFITS

- Wide bandwidth VCO.s
- Voltage Tunable Filters
- Phase Shifters
- Modulators
- VCXOs
- TCXOs

ABSOLUTE MAXIMUM RATINGS AT 25° C (UNLESS OTHERWISE SPECIFIED)						
Rating	Symbol	Value	Unit			
Maximum Working Voltage	V_R	12	V			
Leakage Current @ V _R = 10V	I _R	50	nA			
Storage Temperature	T _{STG}	-65 to +150	∘C			
Operating Temperature	T _{OP}	-55 to +125	°C			

IMPORTANT: For the most current data, consult our website: <u>www.MICROSEMI.com</u> Specifications are subject to change. Consult factory for the latest information.

These devices are ESD sensitive and must be handled using ESD precautions.

¹ Unless otherwise specified, these products are supplied with Gold terminations suitable for RoHS compliant assembly.

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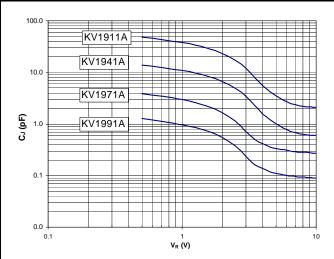


MICROWAVE HYPERABRUPT VARACTORS

٠	ELECTRICAL PARAMETERS @ 25°C (unless otherwise specified)							
	MODEL	$C_J (pF)^2$ f = 1 MHz				TUNING RATIO ²	QUALITY FACTOR ¹	
	NUMBER	V _R = 1V Min	$V_R = 2.5V$ Min - Max	$V_R = 4V$ Max	V _R = 8V Max	C _{J(-1V)} / C _{J(-8V)} Typ	Тур.	
	KV1911A – 00	36	18 - 27	11.8	6	6.0	400	
	KV1951A – 00	26	13 - 20	8.8	4.5	5.8	500	
	KV1921A – 00	17	8.3 - 12.8	5.8	3	5.7	600	
	KV1931A – 00	13	6.3 - 9.8	4.3	2.5	5.6	750	
	KV1941A – 00	9	4.3 - 6.3	2.8	1.5	5.4	900	
	KV1961A – 00	3.8	1.8 - 2.8	1.3	0.8	5.1	1200	
	KV1971A – 00	1.65	0.9 - 1.35	0.6	0.35	4.7	1400	
	KV1981A – 00	1.2	0.6 - 0.9	0.45	0.3	4.3	1600	
	KV1991A – 00	0.6	0.3 - 0.6	0.25	0.15	3.9	1800	

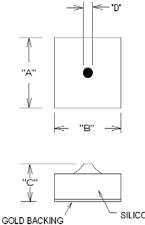
Notes

- Q is determined at V_R = 4V, f =50 MHz by $1/2\pi fRsCj$
- Specs apply to -00 (chip) version. Some limitations apply to packaged versions. Consult factory for more details.



Microsemi offers a wide selection of package options depending on your circuit application. Please consult the factory for assistance.

PACKAGE STYLE 00



Dimension	Nominal		
Α	0.015"		
В	0.015"		
С	0.005"		
D	Depends on Part# Consult Factory for Details		